

isc Silicon NPN Power Transistor

DESCRIPTION

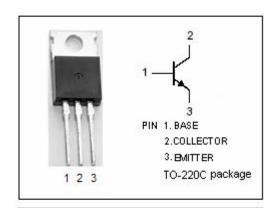
- High Collector Current:: Ic= 12A
- · Low Collector Saturation Voltage
 - : V_{CE(sat)}= 0.4V(Max)@I_C= 5A
- Complement to Type 2SB903
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

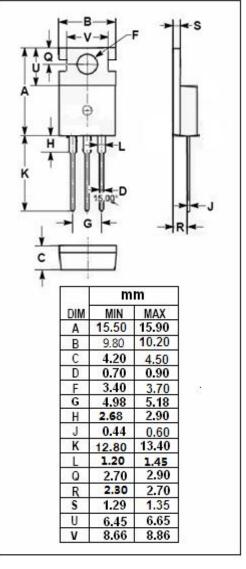
APPLICATIONS

• Designed for relay drivers, high-speed inverters, converters, and other general large-current switching applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage	60	V	
Vceo	Collector-Emitter Voltage	30	V	
V _{EBO}	Emitter-Base Voltage	6	V	
lc	Collector Current-Continuous	12	Α	
Ісм	Collector Current-Peak	20	А	
Pc	Total Power Dissipation @ T _C =25°C	35	W	
	Total Power Dissipation @ T _a =25℃	1.75		
TJ	Junction Temperature	150	$^{\circ}$	
T _{stg}	Storage Temperature Range	-55~150	$^{\circ}$	







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2SD1212

ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I_C = 1mA; R_{BE} = ∞	30			V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	I _C = 1mA ; I _E = 0	60			V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = 1mA ; I _C = 0	6			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 5A; I _B = 0.25A			0.4	V
I _{CBO}	Collector Cutoff Current	V _{CB} = 40V; I _E = 0			0.1	mA
I _{EBO}	Emitter Cutoff Current	V _{EB} = 4V; I _C = 0			0.1	mA
h _{FE-1}	DC Current Gain	I _C = 1A; V _{CE} = 2V	70		280	
h _{FE-2}	DC Current Gain	I _C = 6A; V _{CE} = 2V	30			
f _T	Current-Gain—Bandwidth Product	I _C = 1A; V _{CE} = 5V		120		MHz
Switching times						
ton	Turn-on Time	7		0.2		μ S
t _{stg}	Storage Time	R _L = 2 Ω , V _{CC} = 10V I _C = 5A; I _{B1} = I _{B2} = 0.5A		0.5		μ S
t _f	Fall Time	,		0.03		μS

♦ h_{FE-1} Classifications

Q	R	S
70-140	100-200	140-280

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